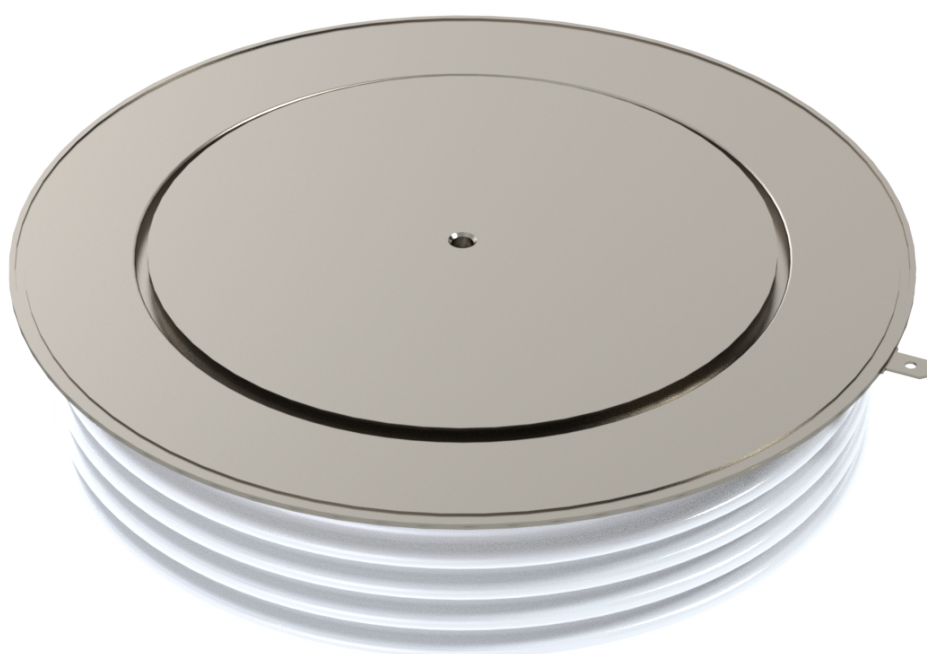


Distributed Gate Thyristor Type SA24SG3968EN

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Date: September, 2020
Data Sheet Issue: 1



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SA	24	SG (rupture rated capsule)	3968	E	N	
-	Voltage Code	Outline Code	Current code	Type code	t _q code	Optional code
t _q code: K = 60μs, L = 65μs, M = 70μs, N = 100μs						

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Absolute Maximum Ratings

VOLTAGE RATINGS		MAXIMUM LIMITS	UNITS
V_{DRM}	Repetitive peak off-state voltage, (note 1)	2400	V
V_{DSM}	Non-repetitive peak off-state voltage, (note 1)	2400	V
V_{DDC}	Maximum DC of-state voltage, (note 1)	1450	V
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2400	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	2500	V
V_{RDC}	Maximum DC revrese voltage, (note 1)	1450	V
note 1)	De-rating factor of 0.13%/°C is applicable for T_j below 25°C		

OTHER RATINGS		MAXIMUM LIMITS	UNITS
$I_{T(AV)M}$	Maximum average on-state current, $T_{sink} = 55^{\circ}C$, (note 1)	4001	A
$I_{T(AV)M}$	Maximum average on-state current, $T_{sink} = 85^{\circ}C$, (note 1)	2691	A
$I_{T(AV)M}$	Maximum average on-state current, $T_{sink} = 85^{\circ}C$, (note 2)	1582	A
$I_{T(RMS)}$	Nominal RMS on-state current, $T_{sink} = 25^{\circ}C$ (note 1)	7988	A
$I_{T(d.c.)}$	D.C. on-state current, $T_{sink} = 25^{\circ}C$, (note 3)	6712	A
I_{TSM}	Peak non-repetitive surge current $t_p = 10ms$, $V_{RM} = 60\%V_{RRM}$, (note4)	66.0	kA
I_{TSM2}	Peak non-repetitive surge current $t_p = 10ms$, $V_{RM} \leq 10V$, (note 4)	72.5	kA
I^2t	I^2t capacity for fusing $t_p = 10ms$, $V_{RM} = 60\%V_{RRM}$, (note 4)	$21.78 \cdot 10^6$	A^2s
I^2t	I^2t capacity for fusing $t_p = 10ms$, $V_{RM} \leq 10V$, (note 4)	$26.28 \cdot 10^6$	A^2s
$(di/dt)_{cr}$	Critical rate of rise of on-state current (Non-repetitive)	1000	$A/\mu s$
	Critical rate of rise of on-state current (repetitive 50Hz, 60s), (note 5)	500	$A/\mu s$
	Critical rate of rise of on-state current (continuous 50Hz), (note 5)	250	$A/\mu s$
V_{RGM}	Peak reverse gate voltage	5	V
$P_{G(AV)}$	Mean forward gate power	4	W
P_{GM}	Peak forward gate power	50	W
T_{jop}	Operating temperature range	-40 to +125	°C
T_{stg}	Storage temperature range	-40 to +150	°C
note 1)	Double-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 2)	Single-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 3)	Double-side cooled		
note 4)	Half-sinewave, 125°C T_j initial		
note 5)	$V_D = 67\%V_{DRM}$, $I_{FG} = 2A$, $t_R \leq 0.5\mu s$, $T_{case} = 125^{\circ}C$		

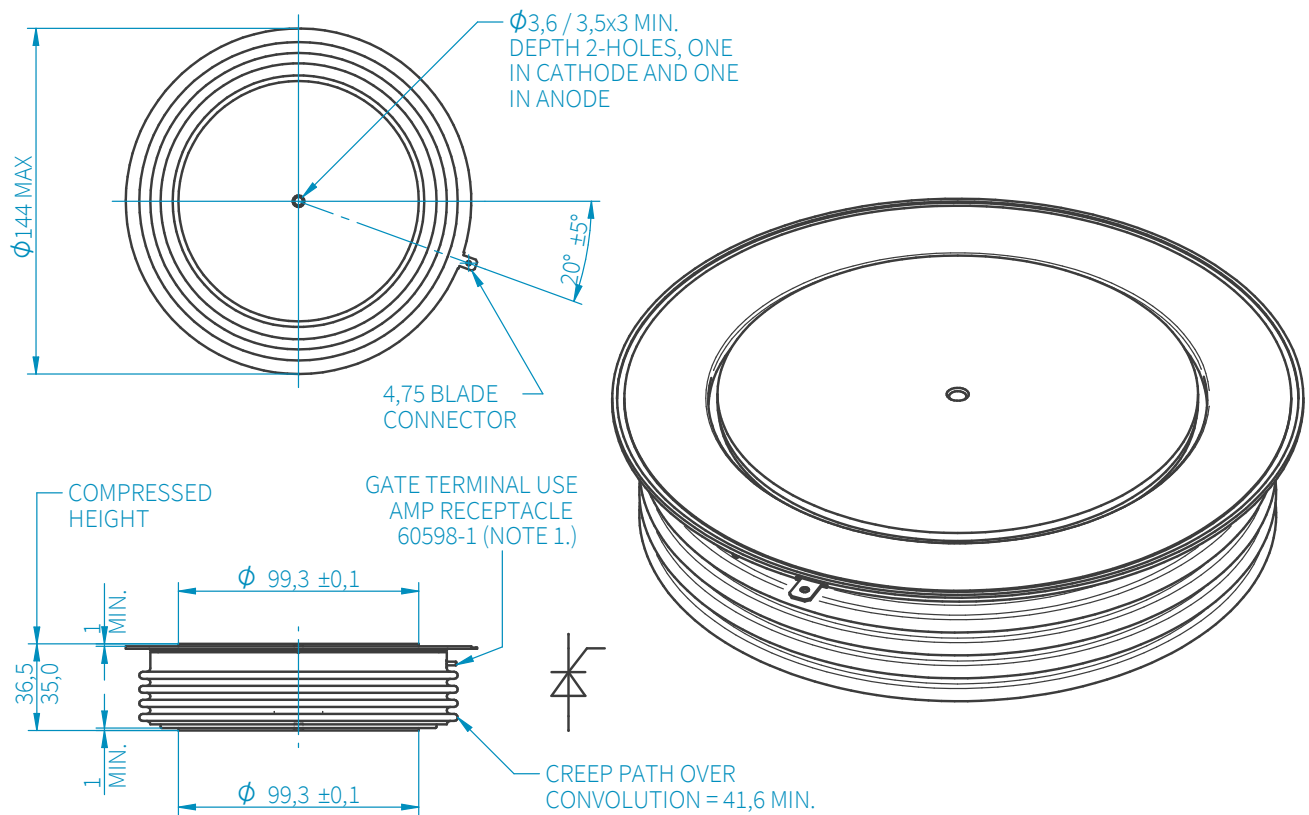
Characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
V_{TM}	Maximum peak on-state voltage	$I_{TM} = 6000A$	-	-	2.20	V
V_{T0}	Threshold voltage		-	-	1.453	V
r_T	Slope resistance		-	-	0.125	mΩ
$(dv/dt)_{CR}$	Critical rate of rise of off-state voltage	$V_D = 80\%V_{DRM}$, Linear ramp, Gate o/c	200	-	-	V/μs
I_{DRM}	Peak off-state current	Rated V_{DRM}	-	-	150	mA
I_{RRM}	Peak reverse current	Rated V_{RRM}	-	-	300	mA
V_{GT}	Gate trigger voltage	$T_j = 25^\circ C$, $V_D = 10V$, $I_T = 3A$	-	-	3.0	V
I_{GT}	Gate trigger current		-	-	600	mA
V_{GD}	Gate non-trigger voltage	Rated V_{DRM}	-	-	0.25	V
I_H	Holding current	$T_j = 25^\circ C$	-	-	1000	mA
t_{GD}	Gate controlled turn-on delay time	$V_D = 67\%V_{DRM}$, $I_{TM} = 4000A$, $di/dt = 60A/\mu s$,	-	0.8	2.0	μs
t_{GT}	Turn-on time	$I_{FG} = 2A$, $t_r = 0.5\mu s$, $T_j = 25^\circ C$	-	2.0	3.0	μs
Q_{RR}	Recovered charge		-	2600	3200	μC
Q_{RA}	Recovered charge, 50% Chord	$I_{TM} = 4000A$, $t_p = 2000\mu s$, $di/dt = 60A/\mu s$,	-	1700	-	μC
I_{RM}	Reverse recovery current	$V_R = 100V$	-	360	-	A
t_{RR}	Reverse recovery time		-	9.5	-	μs
t_{GQ}	Turn-off time (note 2)	$I_{TM} = 4000A$, $t_p = 2000\mu s$, $di/dt = 60A/\mu s$, $V_R = 100V$, $V_{DR} = 67\%V_{DRM}$, $dV_{DR}/dt = 20V/\mu s$	50	-	70	μs
		$I_{TM} = 4000A$, $t_p = 2000\mu s$, $di/dt = 60A/\mu s$, $V_R = 100V$, $V_{DR} = 67\%V_{DRM}$, $dV_{DR}/dt = 200V/\mu s$	60	-	100	μs
R_{thJK}	Thermal resistance, junction to sink (note 3)	Double-side cooled	-	-	6.5	K/kW
		Single-side cooled	-	-	13.0	K/kW
F	Mounting force	(note 3)	81	-	99	kN
W_t	Weight		-	2800	-	g
note 1)	Unless otherwise indicated $T_j = 125^\circ C$					
note 2)	The required t_Q (specified with $dV_{DR}/dt = 200V/\mu s$) is 100μs					
note 3)	For other clamp forces, please consult factory					

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